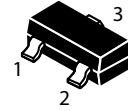
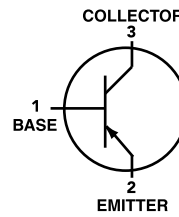


PNP General Purpose Transistors

 Lead(Pb)-Free



SOT-23

MAXIMUM RATINGS(T_a=25°C)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-60	V
Collector-Emitter Voltage	V _{CEO}	-50	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current - Continuous	I _C	-100	mA
Total Device Dissipation T _A =25°C	P _D	200	mW
Junction Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage $I_C = -100\mu A, I_E = 0A$	$V_{(BR)CBO}$	-60	-	-	V
Collector-Emitter Breakdown Voltage $I_C = -1mA, I_B = 0A$	$V_{(BR)CEO}$	-50	-	-	V
Emitter-Base Breakdown Voltage $I_E = 100\mu A, I_C = 0$	$V_{(BR)EBO}$	-5.0	-	-	V
Collector Cutoff Current $V_{CB} = -60V, I_E = 0A$	I_{CBO}	-	-	-0.1	μA
Emitter Cutoff Current $V_{EB} = -5V, I_C = 0A$	I_{EBO}	-	-	-0.1	μA

ON CHARACTERISTICS

Collector-Emitter Saturation Voltage $I_C = -100mA, I_B = -10mA$	$V_{CE(sat)}$	-	-	-0.3	V
Collector-Emitter Voltage $I_C = -1mA, V_{CE} = -6V,$	$V_{BE(on)}$	-	-	-0.68	V
DC Current Transfer Ration $V_{CE} = -6V, I_C = -1mA$	h_{FE}	90	-	600	

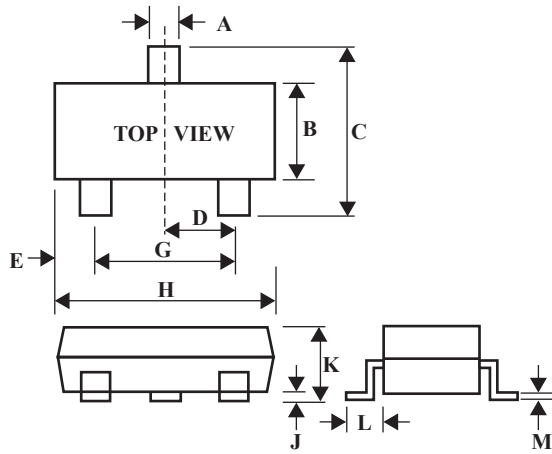
SMALL-SIGNAL CHARACTERISTICS

Transition frequency $V_{CE} = -6V, I_C = -10mA$	f_T	180	-	-	MHz
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CLASSIFICATION h_{FE}

Range	90-180	135-270	200-400	300-600
Marking	M4	M5	M6	M7

SOT-23 Outline Dimension



SOT-23		
Dim	Min	Max
A	0.35	0.51
B	1.19	1.40
C	2.10	3.00
D	0.85	1.05
E	0.46	1.00
G	1.70	2.10
H	2.70	3.10
J	0.01	0.13
K	0.89	1.10
L	0.30	0.61
M	0.076	0.25